

## EMIF10-COM01C2

### EMI Filter including ESD protection

#### Main product characteristics

EMI filtering and ESD protection for:

- Computers and printers
- Communication systems
- Mobile phones

#### **Description**

The EMIF10-COM01C2 is a highly integrated device designed to suppress EMI / RFI noise in all systems subjected to electromagnetic interferences. The EMIF10 Flip-Chip packaging means the package size is equal to the die size.

Additionally, this filter includes an ESD protection circuitry which prevents damage to the application when subjected to ESD surges up to 15 kV.

#### **Benefits**

- EMI symmetrical (I/O) low-pass filter
- Coating resin on flat side
- Very low PCB space consuming: < 6 mm<sup>2</sup>
- Very thin package: 0.65 mm
- High efficiency in ESD suppression on both input and output pins
- High reliability offered by monolithic integration
- Lead free package

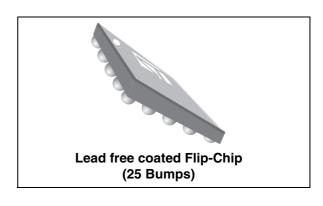
#### Complies with the following standards:

IEC 61000-4-2 level 4

15 kV (air discharge)

8 kV (contact discharge)

TM: IPAD is a trademark of STMicroelctronics



#### Order code

Part Number	Marking	
EMIF10-COM01C2	FE	

Figure 1. Pin configuration (Bump side)

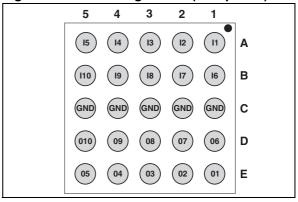
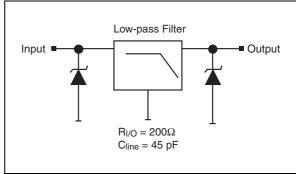


Figure 2. Basic cell configuration



Characteristics EMIF10-COM01C2

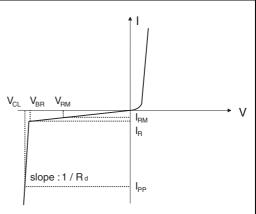
# 1 Characteristics

**Table 1.** Absolute Ratings  $(T_{amb} = 25 \, ^{\circ}C)$ 

Symbol	Parameter and test conditions	Value	Unit
V <sub>PP</sub>	ESD discharge IEC61000-4-2, air discharge ESD discharge IEC61000-4-2, contact discharge	15 8	kV
T <sub>j</sub>	Junction temperature	125	°C
T <sub>op</sub>	Operating temperature range	- 40 to + 85	°C
T <sub>stg</sub>	Storage temperature range	- 55 to + 150	°C

Table 2.Electrical Characteristics  $(T_{amb} = 25 \, ^{\circ}C)$ 

Symbol	Parameter	
V <sub>BR</sub>	Breakdown voltage	
I <sub>RM</sub>	Leakage current @ V <sub>RM</sub>	
V <sub>RM</sub>	Stand-off voltage	
V <sub>CL</sub>	Clamping voltage	V <sub>CL</sub> V <sub>BR</sub> V
R <sub>d</sub>	Dynamic impedance	
I <sub>PP</sub>	Peak pulse current	
R <sub>I/O</sub>	Resistance between Input and Output	slope :
C <sub>line</sub>	Input capacitance per line	

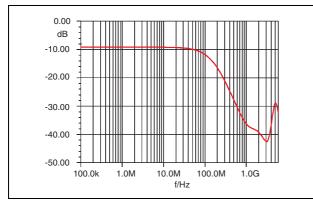


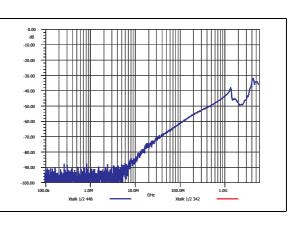
Symbol	Test conditions		Тур.	Max.	Unit
V <sub>BR</sub>	I <sub>R</sub> = 1 mA	6	8	10	V
I <sub>RM</sub>	V <sub>RM</sub> = 3 V per line			500	nA
R <sub>d</sub>	$I_{PP} = 10 \text{ A}, t_p = 2.5 \mu \text{s}$		1		Ω
R <sub>I/O</sub>			200	220	Ω
C <sub>line</sub>	e At 0 V bias		45	50	pF
t <sub>LH</sub>	$V_{input} = 2.8 \text{ V}$ $R_{load} = 100 \text{ k}\Omega$			25	ns

EMIF10-COM01C2 Characteristics

Figure 3. S21(db) attenuation measurement<sup>(1)</sup>

Figure 4. Analog crosstalk





1. Spikes at high frequencies are induced by the PCB layout

Figure 5. ESD response to IEC 61000-4-2 (+15 kV air discharge) on one input (V<sub>in</sub>) and on one output (V<sub>out</sub>)

Figure 6. ESD response to IEC 61000-4-2 (-15 kV air discharge) on one input (V<sub>in</sub>) and on one output (V<sub>out</sub>)

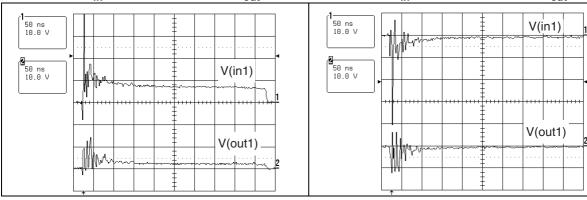
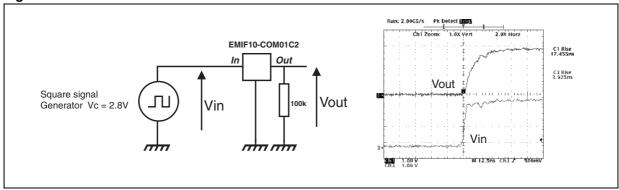


Figure 7. Rise time measurement



Characteristics EMIF10-COM01C2

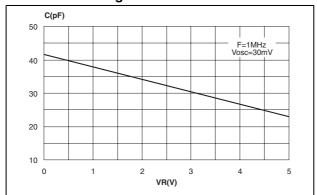
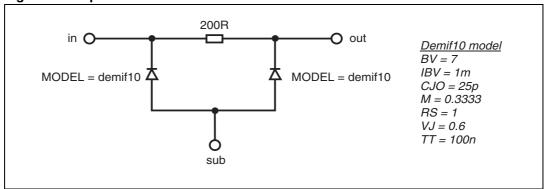


Figure 8. Capacitance versus reverse applied voltage

Figure 9. Aplac model

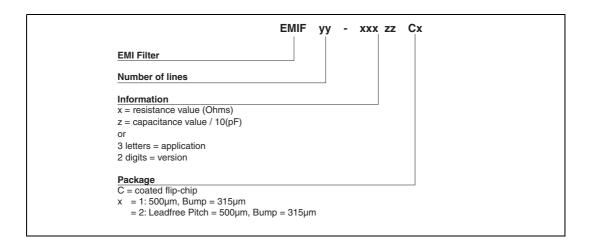


### 1.1 PCB grounding recommendations

4/7

In order to ensure a good efficiency in terms of ESD protection and filtering behavior, we recommend to implement microvias (100  $\mu m$  dia.) between the GND bumps and the GND layer. GND bumps can be connected together in PCB layer 1, and in addition, if possible, use through hole vias (200  $\mu m$  dia.) in both sides of filter to improve contact to GND (layer). This layout will minimize the distance to the ground and thus parasitic inductances. In addition, we recommend to have GND plane wherever possible.

# 2 Ordering Information Scheme



# 3 Package information

Figure 10. Flip-Chip package dimensions

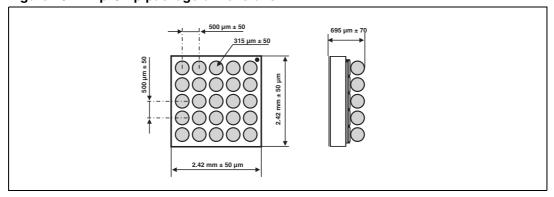
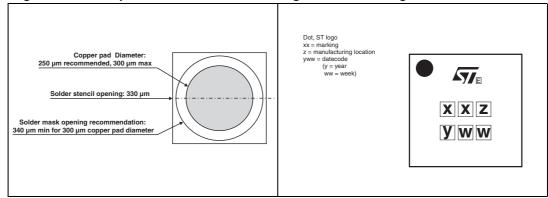


Figure 11. Foot print recommendations Figure 12. Marking



577

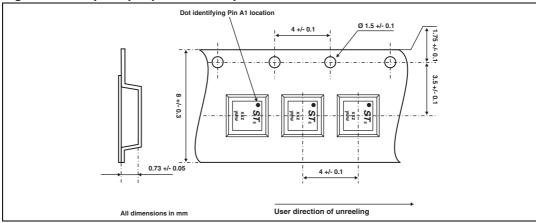


Figure 13. Flip-Chip tape and reel specification

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Note: More informations are available in the application notes:

AN1235: "Flip-Chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

### 4 Ordering information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
EMIF10-COM01C2	FE	Flip-Chip	8.3 mg	5000	Tape and reel

## 5 Revision history

Date	Revision	Description of Changes
12-Jul-2005	1	First issue.
12-Aug-2005	2	Lead free added in Benefits on page 1. ECOPACK statement added on page 6.
27-Jan-2006	3	Improved graphics to show coating. Updated attenuation measurement graphic (Figure 3). Weight corrected.
04-Apr-2006	4	Reformatted to current standard. Pin identification in Figure 1 updated.

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT DESIGNED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

